Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.180 inches

Terminal Length:

1.500 inches

Overall Diameter:

0.370 inches

End Application:

Group programmer

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

75.0 collector to base voltage/static/emitter open all transistor and 40.0 collector to emitter voltage/static/base open all transistor and 6.0 emitter to base voltage, static, collector open all transistor

Current Rating Per Characteristic:

600.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector all transistor

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

All transistor junction pattern arrangement: npn

Nuclear Hardness Critical Feature:

Hardened

Test Data Document:

81205-bacs8a drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

6 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A110a0